

0.8 A Three-quadrant triacs high commutation

Rev. 01 — 18 January 2008

Product data sheet

### **Product profile**

### 1.1 General description

Passivated, guaranteed commutation, sensitive gate triacs in a SOT54 plastic package

### 1.2 Features

- Guaranteed commutation performance
  Easily interfaced with low power drivers at each gate sensitivity
- Sensitive gate

including microcontrollers

### 1.3 Applications

Motor control

Solenoid drivers

### 1.4 Quick reference data

- $V_{DRM} \le 600 \text{ V (BTA2008-600D)}$
- $V_{DRM} \le 600 \text{ V (BTA2008-600E)}$
- $V_{DRM} \le 800 \text{ V (BTA2008-800D)}$
- $V_{DRM} \le 800 \text{ V (BTA2008-800E)}$
- $I_{TSM} \le 9 \text{ A (t = 20 ms)}$

- $I_{GT} \le 5 \text{ mA (BTA2008-600D)}$
- $I_{GT} \le 5 \text{ mA (BTA2008-800D)}$
- $I_{GT} \le 10 \text{ mA (BTA2008-600E)}$
- $I_{GT} \le 10 \text{ mA (BTA2008-800E)}$
- $I_{T(RMS)} \le 0.8 A$

# **Pinning information**

Table 1. **Pinning** 

	9		
Pin	Description	Simplified outline	Graphic symbol
1	main terminal 2 (T2)		<b>N</b> 1
2	gate (G)		T2—T1
3	main terminal 1 (T1)		sym051
		SOT54 (TO-92)	



# 3. Ordering information

### Table 2. Ordering information

Type number	Package					
	Name	Description	Version			
BTA2008-600D	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
BTA2008-600E						
BTA2008-800D						
BTA2008-800E						

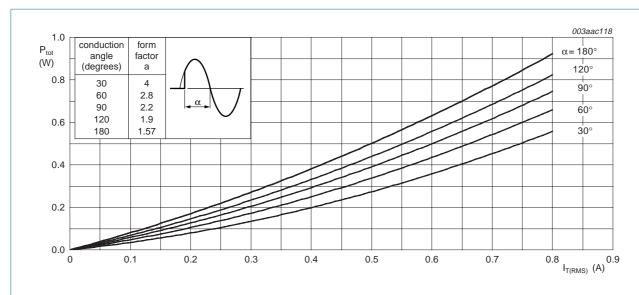
# 4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

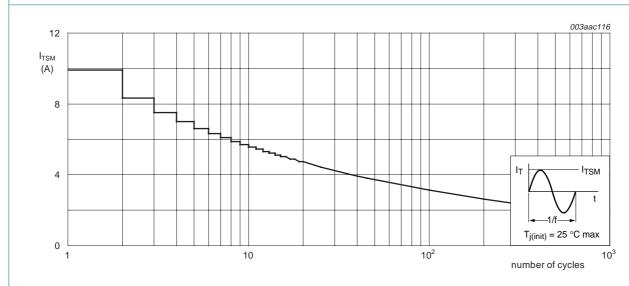
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage	BTA2008-600D; BTA2008-600E	<u>[1]</u> _	600	V
		BTA2008-800D; BTA2008-800E	-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; $T_{lead} \le 70$ °C; see Figure 4 and 5	-	0.8	Α
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; $T_j = 25 ^{\circ}\text{C}$ prior to surge; see Figure 2 and 3			
		t = 20 ms	-	9	Α
		t = 16.7 ms	-	9.9	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms	-	0.41	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_{TM} = 1.5 \text{ A}; I_G = 20 \text{ mA};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	100	A/μs
I <sub>GM</sub>	peak gate current		-	1	Α
$P_{GM}$	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.1	W
T <sub>stg</sub>	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

<sup>[1]</sup> Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6  $A/\mu s$ .



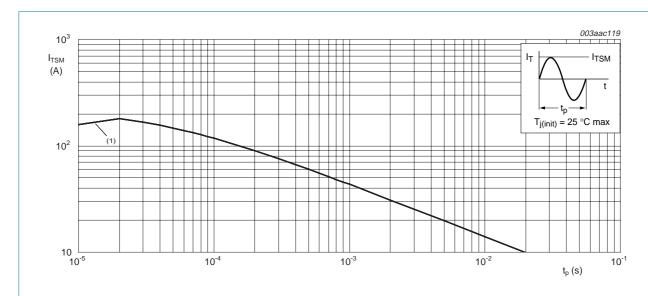
 $\alpha$  = conduction angle

Fig 1. Total power dissipation as a function of RMS on-state current; maximum values



f = 50 Hz

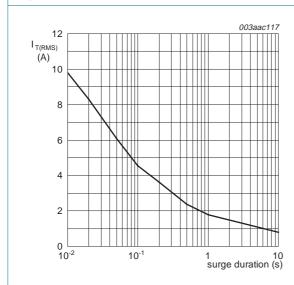
Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



 $t_p \leq 20 \ ms$ 

(1) dl<sub>T</sub>/dt limit

Fig 3. Non-repetitive peak on-state current as a function of pulse duration; maximum values



f = 50 Hz T<sub>lead</sub> = 70 °C

Fig 4. RMS on-state current as a function of surge duration; maximum values

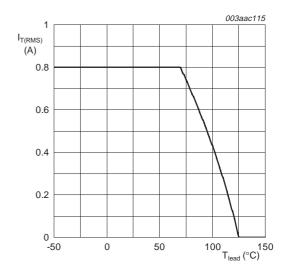
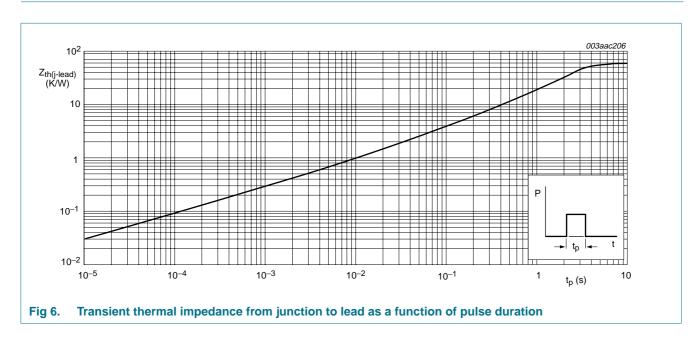


Fig 5. RMS on-state current as a function of lead temperature; maximum values

### 5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-lead})}$	thermal resistance from junction to lead	full cycle; see Figure 6	-	-	60	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	printed circuit board mounted; lead length 4 mm	-	150	-	K/W



## 6. Static characteristics

Table 5. Static characteristics

 $T_i = 25 \,^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	BTA2008-600D BTA2008-800D			BTA2008-600E BTA2008-800E			Unit
			Min	Тур	Max	Min	Тур	Max	
$I_{GT}$	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 8}}{}$							
		T2+ G+	0.25	-	5	0.5	-	10	mΑ
		T2+ G-	0.25	-	5	0.5	-	10	mΑ
		T2- G-	0.25	-	5	0.5	-	10	mΑ
I <sub>L</sub> latching current	$V_D = 12 \text{ V; } I_{GT} = 0.1 \text{ A;}$ see Figure 10								
		T2+ G+	-	-	10	-	-	12	mΑ
	T2+ G-	-	-	20	-	-	20	mΑ	
		T2- G-	-	-	10	-	-	12	mΑ
I <sub>H</sub>	holding current	$V_D = 12 \text{ V; } I_{GT} = 0.1 \text{ A;}$ see Figure 11	-	-	10	-	-	12	mA
$V_{T}$	on-state voltage	I <sub>T</sub> = 0.85 A; see <u>Figure 9</u>	-	1.35	1.6	-	1.35	1.6	V
$V_{GT}$	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 7}}{}$	-	0.9	2	-	0.9	2	V
		$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 ^{\circ}\text{C}$	0.2	0.3	-	0.2	0.3	-	V
$I_D$	off-state current	$V_D = V_{DRM(max)}$ ; $T_j = 125  ^{\circ}C$	-	0.1	0.5	-	0.1	0.5	mΑ

# 7. Dynamic characteristics

Table 6. Dynamic characteristics

Symbol	Parameter	ameter Conditions		BTA2008-600D BTA2008-800D			BTA2008-600E BTA2008-800E		
			Min	Тур	Max	Min	Тур	Max	
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)};$ $T_j = 125 ^{\circ}C;$ exponential waveform; gate open circuit	200	-	-	600	-	-	V/μs
dI <sub>com</sub> /dt	rate of change of commutating current	$V_{DM}$ = 400 V; $T_j$ = 125 °C; $I_{T(RMS)}$ = 0.8 A; dV/dt = 10 V/ $\mu$ s; gate open circuit	0.5	-	-	1.6	-	-	A/ms
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM} = 1 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	-	2	-	μs

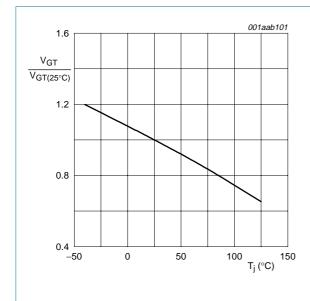
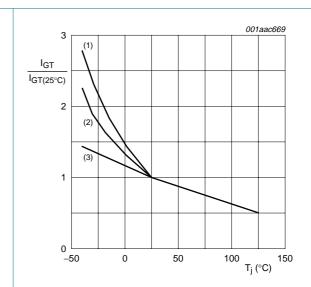
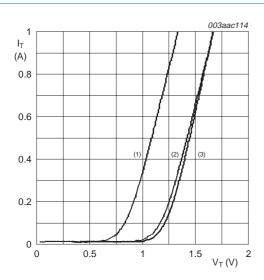


Fig 7. Normalized gate trigger voltage as a function of junction temperature



- (1) T2-G-
- (2) T2+ G-
- (3) T2+ G+

Fig 8. Normalized gate trigger current as a function of junction temperature



 $V_0 = 0.835 \text{ V}$ 

 $R_s = 0.5 \Omega$ 

(1)  $T_j = 125 \,^{\circ}C$ ; typical values

(2)  $T_i = 125 \,^{\circ}C$ ; maximum values

(3)  $T_i = 25$  °C; maximum values

Fig 9. On-state current as a function of on-state voltage

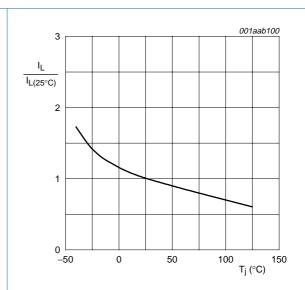


Fig 10. Normalized latching current as a function of junction temperature

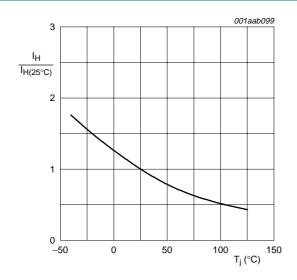
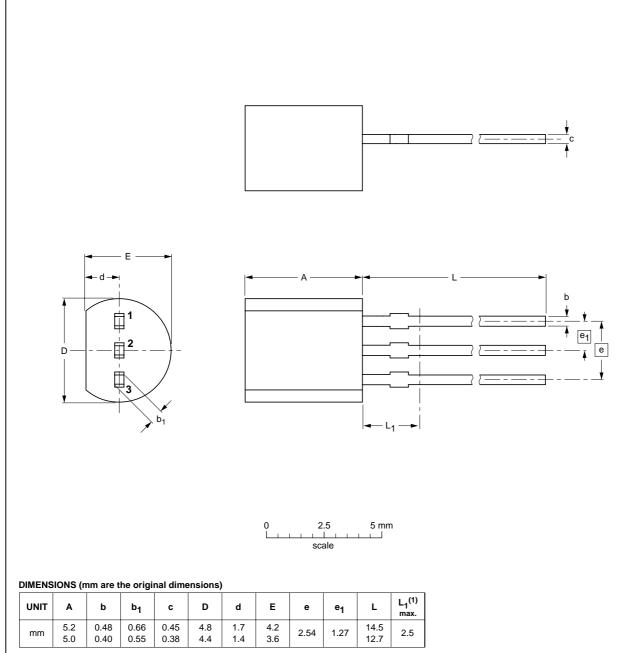


Fig 11. Normalized holding current as a function of junction temperature

#### **Package outline** 8.

### Plastic single-ended leaded (through hole) package; 3 leads

SOT54



1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A		<del>-04-06-28</del> 04-11-16

Fig 12. Package outline SOT54 (TO-92)

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0.8 A Three-quadrant triacs high commutation

# 9. Revision history

### Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA2008_SER_D_E_1	20080118	Product data sheet	-	-

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### 0.8 A Three-quadrant triacs high commutation

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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11 of 12

### 0.8 A Three-quadrant triacs high commutation

### 12. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications
1.4	Quick reference data
2	Pinning information 1
3	Ordering information 2
4	Limiting values 2
5	Thermal characteristics 5
6	Static characteristics 6
7	Dynamic characteristics
8	Package outline 9
9	Revision history 10
10	Legal information
10.1	Data sheet status
10.2	Definitions
10.3	Disclaimers
10.4	Trademarks11
11	Contact information 11
12	Contonto 12

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